TOSHIBA Transistor Silicon PNP Triple Diffused Type

# 2SA2034

### **High-Voltage Switching Applications**

High voltage : V<sub>CBO</sub> = −400 V

• High speed :  $t_f = 0.3 \, \mu s \, (max) \, (I_C = -1.0 \, A)$ 

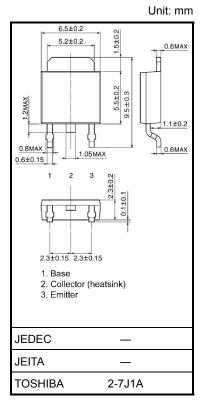
### Absolute Maximum Ratings (Tc = 25°C)

Characteristic			Symbol	Rating	Unit	
Collector-base voltage			V <sub>CBO</sub>	-400	٧	
Collector-emitter voltage			V <sub>CEO</sub>	-400	V	
Emitter-base voltage			V <sub>EBO</sub>	-7	V	
Collector current	DC		Ic	-2	А	
	Pulse		I <sub>CP</sub>	-4		
Base current			lΒ	-1	Α	
Collector power dissipation		Ta = 25°C	Pc	1	W	
		Tc = 25°C	FC	15		
Junction temperature			Tj	150	°C	
Storage temperature range			T <sub>stg</sub>	-55~150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e.

operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report

and estimated failure rate, etc).

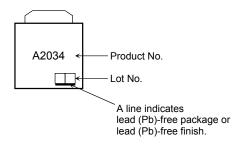


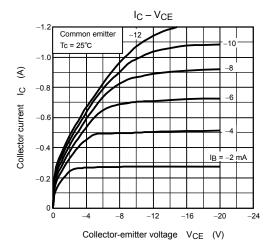
Weight: 0.36 g (typ.)

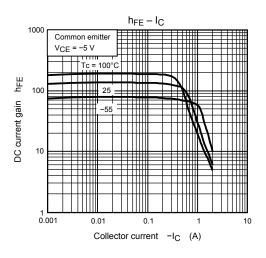
## **Electrical Characteristics (Tc = 25°C)**

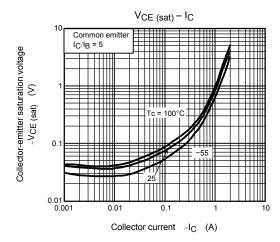
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cutoff current		I <sub>CBO</sub>	V <sub>CB</sub> = -400 V, I <sub>E</sub> = 0	_	_	-10	μΑ
Emitter cutoff current		I <sub>EBO</sub> V <sub>EB</sub> = -7 V, I <sub>C</sub> = 0		_	_	-1	μΑ
Collector-emitter breakdown voltage		V (BR) CEO	I <sub>C</sub> = -10 mA, I <sub>B</sub> = 0	-400	_	_	V
DC current gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -1 mA	80	_	_	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -0.1 A	80	_	240	
Collector-emitter saturation voltage		V <sub>CE</sub> (sat)	I <sub>C</sub> = -0.5 A, I <sub>B</sub> = -0.1 A	_	_	-1.0	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	I <sub>C</sub> = -0.5 A, I <sub>B</sub> = -0.1 A	_	_	-1.5	V
Switching time	Rise time	t <sub>r</sub>	$\begin{array}{c c} 20 \mu \text{ s} \\ \hline \downarrow & \\ \hline \downarrow & \\ \hline \downarrow I_{B2} & V_{CC} = -200V \end{array}$	_	_	0.3	
	Storage time	t <sub>stg</sub>	$I_{B1}$ Output	_	_	2.5	μs
	Fall time	tf	Input $V$ $I$	_	_	0.3	

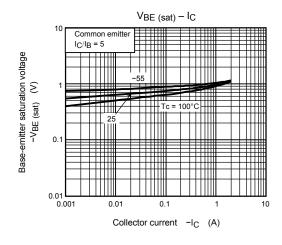
### Marking

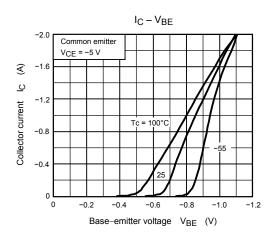




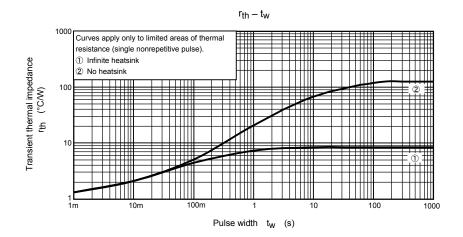


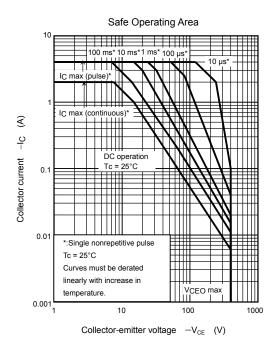






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